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Question Paper Code: 53305

B.E./B.Tech. DEGREE EXAMINATION, MAY 2022

Third Semester

Electrical and Electronics Engineering

15UEE305-SEMICONTUCTOR DEVICES AND CIRCUITS

	(Regulati	on 2015)		
ation: Three hours			Maximum: 100 Marks	
	PART A - (10 x	1 = 10 Marks		
Since diodes are desi	troyed by excessive cur	rent, circuits must ha	ave CO1- R	
(a) Higher voltage so	ources	(b) Current limiting	ng resistors	
(c) More dopants		(d) Higher current	sources	
2. When a diode is forward biased, the voltage across it			CO1- R	
(a) is inversely propo	ortional to the current	(b) remains a	approximately the same	
(c) is directly proportional to the source voltage (d) is directly proportional to the c				
3. A current ratio of I_C/I_E is usually less than one and is called			CO2- R	
(a) Beta	(b) Theta	(c) Alpha	(d) Omega	
. A transistor may be used as a switching device or as a			CO2-R	
(a) Fixed resistor	(b) Turning device	(c) Rectifier	(d) Variable resistor	
A JFET has	power gain		CO3- R	
(a) Small	(b) Very High	(c) Very Small	(d) High	
The input impedance	e of a MOSFET is of the	e order of	CO3- R	
(a) Ohms		(b) A few hundred	lohms	
(c) Kilo ohms		(d) Several Mega	ohms	
	(a) Higher voltage so (c) More dopants When a diode is forw (a) is inversely propor (c) is directly propor A current ratio of I _C / (a) Beta A transistor may be a (a) Fixed resistor A JFET has (a) Small The input impedance (a) Ohms	PART A - (10 x Since diodes are destroyed by excessive cur (a) Higher voltage sources (c) More dopants When a diode is forward biased, the voltage (a) is inversely proportional to the current (c) is directly proportional to the source voltage (a) Beta (b) Theta A transistor may be used as a switching dev (a) Fixed resistor (b) Turning device A JFET has power gain (a) Small (b) Very High The input impedance of a MOSFET is of the (a) Ohms	PART A - (10 x 1 = 10 Marks) Since diodes are destroyed by excessive current, circuits must he (a) Higher voltage sources (b) Current limiting (c) More dopants (d) Higher current When a diode is forward biased, the voltage across it (a) is inversely proportional to the current (b) remains at (c) is directly proportional to the source voltage (d) is directly A current ratio of I _C /I _E is usually less than one and is called (a) Beta (b) Theta (c) Alpha A transistor may be used as a switching device or as a (a) Fixed resistor (b) Turning device (c) Rectifier A JFET has power gain (a) Small (b) Very High (c) Very Small The input impedance of a MOSFET is of the order of (a) Ohms (b) A few hundred	

7.	An	oscillator employs	_feedback.		CO4- R
	(a) I	Positive	(b) Negative		
	(c) l	Neither positive nor negative	(d) Unity		
8.	An	An oscillator differs from an amplifier because it			CO4- R
	(a) l	Has more gain	(b) Requires no input sign	ıal	
	(c) l	Requires no d.c. supply	(d) Always has the same i	nput	
9.	In p	ulse width modulation,			CO5- R
	(a) S	Synchronization is not required betwee	n transmitter and receiver		
	(b) A	Amplitude of the carrier pulse is varied			
	(c) l	Instantaneous power at the transmitter i	s constant		
	(d)]	None of the above			
10.	The	sampling technique having the minimum	um noise interference is		CO5- R
	(a) l	Instantaneous sampling	(b) Natural sampling		
	(c) l	Flat top sampling	(d) All of the above		
		PART – B (5	x 2= 10Marks)		
11.	. Sketch the V-I characteristics of Zener diode.			CO1- R	
12.	. State the significance of optocouplers.				CO2-R
13.	Giv	e the significance of Darlington connec	etion.		CO3- R
14.	List	out the various conditions satisfied for	oscillation in electronic circ	uits.	CO4- R
15.	Wha	at are the merits of Schmitt trigger circ	uits?		CO5- R
		PART - C (5 x 16= 80 Marks)		
16.	(a)	Analyze the variousswitching charact and comment on each.	eristicsfor HWRand FWR	CO1- Ap	p (16)
		Or			
	(b)	Obtain the PN junction diode VI che the following factors of it: R _d , tendiffusion currents.		•	op (16)

17. (a) Apply the relationship between α , β and γ - hybrid model and also CO2- App (16)derive its analytical expressions. Or (b) Analyze the Input and Output characteristics for CC BJT CO2-App (16)configuration with suitable waveforms. 18. (a) Derive the JFET Characteristics and parameters with necessary CO3- Ana (16)assumptions. Or (b) Analyze the construction of MOSFET enhancement and depletion CO3- Ana (16)mode and also plot its various characteristics. Elaborately give the points regarding the construction and CO4-U 19. (a) (16)working of Colpitts oscillator. Or (b) Explain common mode and differential mode amplifiers. CO4- U (16)(a) Discuss the various clipper and clamper circuits construction and CO5-U 20. (16)working along with its characteristics. Or Illustrate the construction and working of UJT based saw tooth CO5-U (16)oscillators.